

MLP 3.3x3.3

MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			-150	V	
V _{GS}	Gate to Source Voltage			±25	V	
I _D	Drain Current -Continuous	T _C = 25 °C		-9		
	-Continuous	T _A = 25 °C	(Note 1a)	-2.7	Α	
	-Pulsed			-20		
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	121	mJ	
P _D	Power Dissipation	T _C = 25 °C		40	w	
	Power Dissipation	T _A = 25 °C	(Note 1a)	2.3	vv	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to + 150	°C	

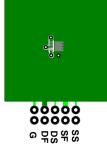
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	3.1	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient (Note 1a) 53	C/W

Package Marking and Ordering Information

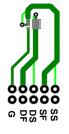
Device Marking	Device	Package	Reel Size	Tape Width	Quantity	
FDMC86261P	FDMC86261P	Power 33	13"	12 mm	3000 units	

FDMC86261P P-Channel PowerTrench[®] MOSFET

0	al Characteristics $T_J = 25 \text{ °C}$ unle			.		11.11	
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	icteristics						
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = -250 \ \mu A, \ V_{GS} = 0 \ V$	-150			V	
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	I_D = -250 µA, referenced to 25 °C		-132		mV/°C	
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -120 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			-1	μΑ	
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA	
On Chara	cteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = -250 \ \mu A$	-2	-3	-4	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_{J}}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, referenced to 25 °C		6		mV/°C	
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = -10 V, I _D = -2.4 A		130	160		
		$V_{GS} = -6 \text{ V}, \text{ I}_{D} = -2.2 \text{ A}$		141	185	mΩ	
		V _{GS} = -10 V, I _D = -2.4 A,T _J = 125 °C		218	269		
9 _{FS}	Forward Transconductance	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -2.4 \text{ A}$		9		S	
C _{iss} C _{oss}	Input Capacitance Output Capacitance	V _{DS} = -75 V, V _{GS} = 0 V, f = 1 MHz		1021 87	1360 120	pF pF	
C _{oss} C _{rss}	Reverse Transfer Capacitance			4.7	120	pF	
R _g	Gate Resistance		0.1	1.7	3.4	Ω	
Switching	g Characteristics			44			
t _{d(on)}	Turn-On Delay Time			11	20	ns	
t _r	Rise Time	$V_{DD} = -75 \text{ V}, \text{ I}_D = -2.4 \text{ A},$ $V_{GS} = -10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		2.4	10	ns	
t _{d(off)}	Turn-Off Delay Time Fall Time	$V_{GS} = -10 V$; $N_{GEN} = 0.22$		18 9.2	33 20	ns	
t _f	Total Gate Charge	$V_{\rm ext} = 0.00$ to -10.00		9.2 17	20	ns nC	
Q _{g(TOT)} Q _{g(TOT)}	Total Gate Charge	$\frac{V_{GS} = 0 \text{ V to -10 V}}{V_{GS} = 0 \text{ V to -6 V}} V_{DD} = -75 \text{ V},$ $I_D = -2.4 \text{ A}$		11	16	nC	
Q_{gs}	Total Gate Charge	$I_{\rm D} = -2.4 {\rm A}$		4.2	10	nC	
Q _{gd}	Gate to Drain "Miller" Charge			3.7		nC	
	urce Diode Characteristics						
		$V_{GS} = 0 V, I_{S} = -2.4 A$ (Note 2)		-0.81	-1.3	V	
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = -1.9 A$ (Note 2)		-0.80	-1.2	V	
				81	130	ns	
t _{rr}	Reverse Recovery Time	– I _F = -2.4 A, di/dt = 100 A/μs		01	150	113	



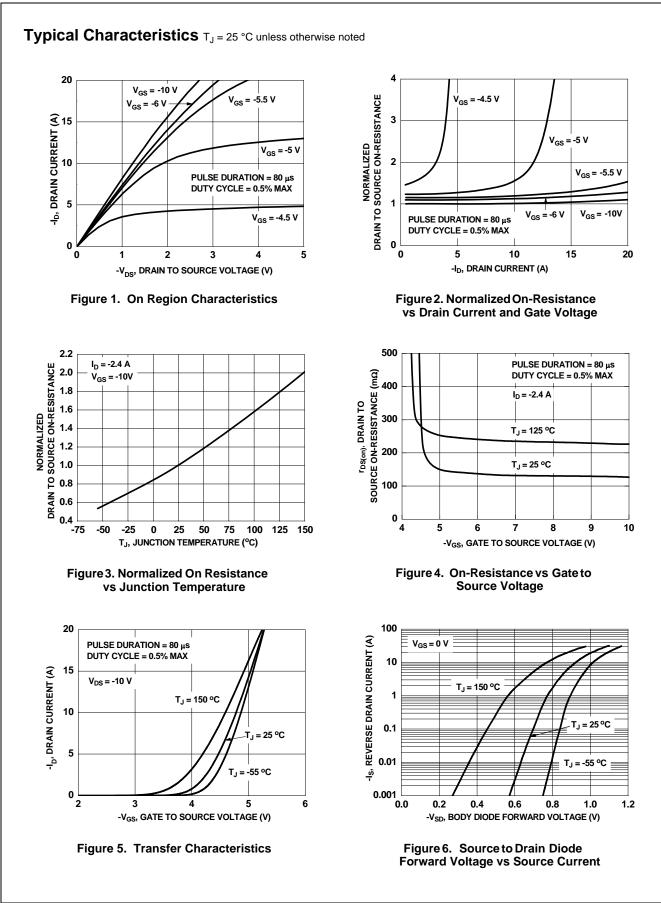
a) 53 °C/W when mounted on a 1 in² pad of 2 oz copper



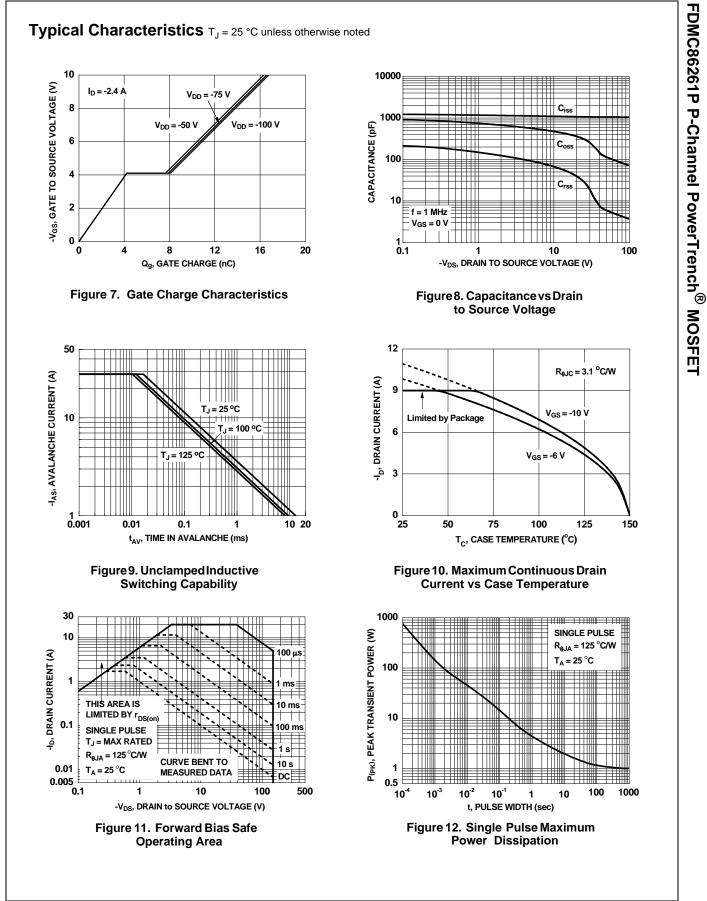
b) 125 °C/W when mounted on a minimum pad of 2 oz copper

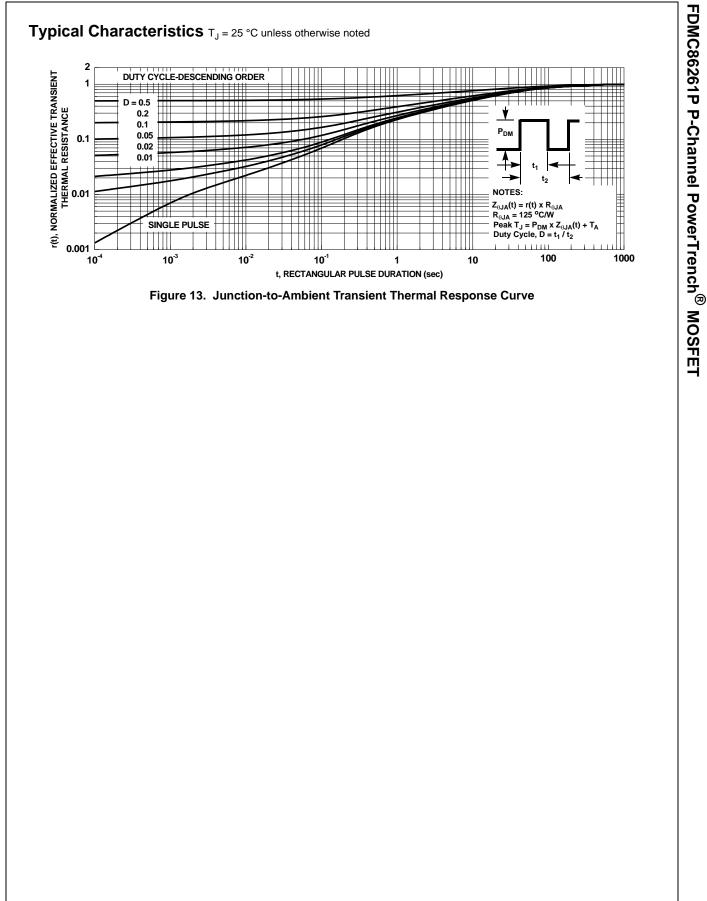
2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0%.

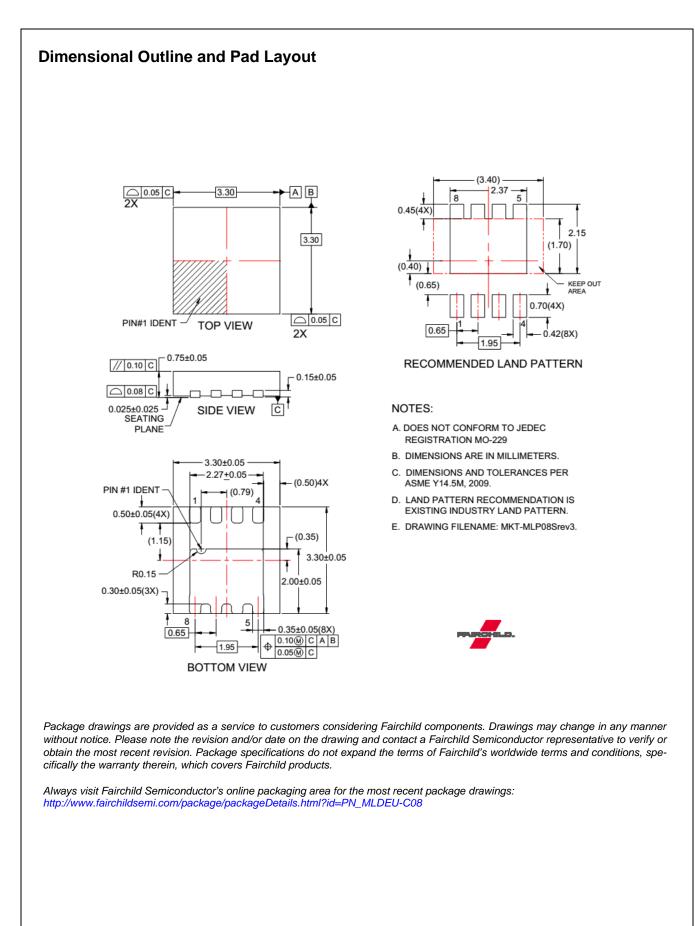
3. Starting $T_J = 25$ °C; P-ch: L = 3 mH, $I_{AS} = -9$ A, $V_{DD} = -150$ V, $V_{GS} = -10$ V. 100% test at L = 0.1 mH, $I_{AS} = -28$ A.



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